- Advanced LinCMOS<sup>™</sup> Silicon-Gate Technology
- Easily interfaced to Microprocessors
- **On-Chip Data Latches**
- Monotonicity Over Entire A/D Conversion Range
- Segmented High-Order Bits Ensure Low-Glitch Output
- **Designed to Be interchangeable With** Analog Devices AD7524, PMI PM-7524, and **Micro Power Systems MP7524**
- **Fast Control Signaling for Digital Signal Processor Applications Including Interface** With SMJ320

| KEY PERFORMANCE SPECIFICATIONS      |             |  |  |  |  |
|-------------------------------------|-------------|--|--|--|--|
| Resolution                          | 8 Bits      |  |  |  |  |
| Linearity error                     | 1/2 LSB Max |  |  |  |  |
| Power dissipation at $V_{DD} = 5 V$ | 5 mW Max    |  |  |  |  |
| Settling time                       | 100 ns Max  |  |  |  |  |
| Propagation delay                   | 80 ns Max   |  |  |  |  |



The AD7524M is an Advanced LinCMOS<sup>™</sup> 8-bit digital-to-analog converter (DAC) designed for easy interface to most popular microprocessors.

The AD7524M is an 8-bit multiplying DAC with input latches and with a load cycle similar to the write cycle of a random access memory. Segmenting the high-order bits minimizes glitches during changes in the most-significant bits, which produce the highest glitch impulse. The AD7524M provides accuracy to 1/2 LSB without the need for thin-film resistors or laser trimming, while dissipating less than 5 mW typically.

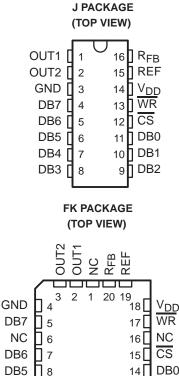
Featuring operation from a 5-V to 15-V single supply, the AD7524M interfaces easily to most microprocessor buses or output ports. Excellent multiplying (2 or 4 quadrant) makes the AD7524M an ideal choice for many microprocessor-controlled gain-setting and signal-control applications.

The AD7524M is characterized for operation from -55°C to 125°C.

| AVAILABLE OPTIONS |  |          |  |  |  |
|-------------------|--|----------|--|--|--|
|                   | PAC  | KAGE     |  |  |  |
| TA                | CERAMIC CHIP<br>CARRIER<br>(FK) CERAMIC DIP<br>(J) |          |  |  |  |
| -55°C to 125°C    | AD7524MFK  | AD7524MJ |  |  |  |

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9 10 11 12 13

DB4 DB3 DB2 DB2 DB1

NC-No internal connection

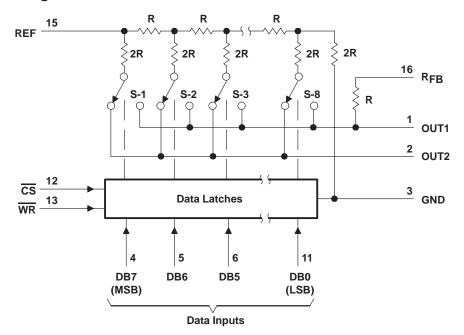
8

DB0 14

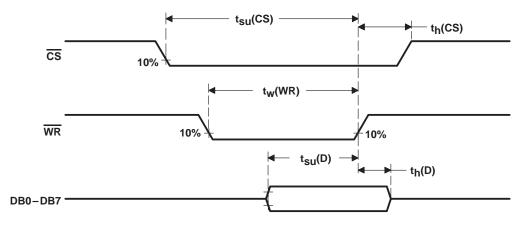
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#### AD7524M Advanced LinCMOS<sup>TM</sup> 8-BIT MULTIPLYING DIGITAL-TO-ANALOG CONVERTER SGLS028A – SEPTEMBER 1989 – REVISED MARCH 1995

### functional block diagram



# operating sequence





#### AD7524M Advanced LinCMOS<sup>™</sup> 8-BIT MULTIPLYING **DIGITAL-TO-ANALOG CONVERTER** SGLS028A - SEPTEMBER 1989 - REVISED MARCH 1995

#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

| Supply voltage range, $V_{DD}$  | . ±25 V<br>D+0.3 V<br>. ±25 V<br>. 10 μA<br>o 125°C |
|---|---|
| Operating free-air temperature range, $T_A$ $-55^{\circ}C$ toStorage temperature range, $T_{stg}$ $-65^{\circ}C$ toCase temperature for 60 seconds, $T_C$ : FK packageLead temperature 1,6 mm (1/16 inch) from case for 60 seconds: J package | o 150°C<br>260°C                                    |

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### recommended operating conditions

|  | V <sub>DD</sub> = 5 V |     | V <sub>DD</sub> = 15 V |      |     | UNIT |    |  |
|--|-----------------------|-----|------------------------|------|-----|------|----|--|
|  | MIN                   | NOM | MAX                    | MIN  | NOM | MAX  |    |  |
| Supply voltage, V <sub>DD</sub>                | 4.75                  | 5   | 5.25                   | 14.5 | 15  | 15.5 | V  |  |
| Reference voltage, V <sub>ref</sub>            |                       | ±10 |                        |      | ±10 |      | V  |  |
| High-level input voltage, VIH                  | 2.4                   |     |                        | 13.5 |     |      | V  |  |
| Low-level input volage, VIL                    |                       |     | 0.8                    |      |     | 1.5  | V  |  |
| CS setup time, t <sub>su(CS)</sub>             | 40                    |     |                        | 40   |     |      | ns |  |
| CS hold time, th(CS)                           | 0                     |     |                        | 0    |     |      | ns |  |
| Data bus input setup time, t <sub>su(D)</sub>  | 25                    |     |                        | 25   |     |      | ns |  |
| Data bus input hold time, t <sub>h(D)</sub>    | 10                    |     |                        | 10   |     |      | ns |  |
| Pulse duration, WR low, tw(WR)                 | 40                    |     |                        | 40   |     |      | ns |  |
| Operating free-air temperature, T <sub>A</sub> | -55                   |     | 125                    | -55  |     | 125  | °C |  |



# AD7524M Advanced LinCMOS<sup>™</sup> 8-BIT MULTIPLYING **DIGITAL-TO-ANALOG CONVERTER**

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# electrical characteristics over recommended operating free-air temperature range, $V_{ref}$ = 10 V, OUT1 and OUT2 at GND (unless otherwise noted)

|                  | PARAMETER                       |                                   | TEST CONDITIONS   |   | V          | DD = 5 \ | /    | VD   | D = 15 \ | V    | UNIT       |    |
|------------------|---------------------------------|-----------------------------------|---|---|------------|----------|------|------|----------|------|------------|----|
|                  | PARAMETER                       |                                   |   |   | MIN        | TYP      | MAX  | MIN  | TYP      | MAX  | UNIT       |    |
|                  | lus lieb level is not sument    |                                   |   | Full-range  |            |          | 10   |      |          | 10   | A          |    |
| ін               | High-level input cu             | Inent                             | $V_I = V_{DD}$  | 25°C  |            |          | 1    |      |          | 1    | μA         |    |
| 1                | Low-level input cu              |                                   | V1 = 0  | Full-range  |            |          | -10  |      |          | -10  |            |    |
| μ                | Low-level input cu              | nent                              | VI = 0  | 25°C  |            |          | -1   |      |          | -1   | μA         |    |
|                  |                                 | OUT1                              | DB0–DB <u>7 at</u> 0,<br>WR and CS at 0 V   | Full-range  |            |          | ±400 |      |          | ±200 |            |    |
|                  | Output leakage                  |                                   | V <sub>ref</sub> = ±10 V  | 25°C  |            |          | ±50  |      |          | ±50  | -          |    |
| l <sub>pkg</sub> | g current                       | current                           | OUT2  | DB0–DB <u>7</u> at V <sub>DD,</sub><br>WR and CS at 0 | Full-range |          |      | ±400 |          |      | ±200       | nA |
|                  |                                 |                                   | $V_{ref} = \pm 10 V$  | 25°C  |            |          | ±50  |      |          | ±50  |            |    |
|                  | Quiescent                       |                                   | DB0–DB7 at V <sub>IH</sub> min or V <sub>II</sub>                                     | max   |            |          | 2    |      |          | 2    | mA         |    |
| IDD              | Supply current Standby          | DB0–DB7 at 0 V or V <sub>DD</sub> | Full-range  |   |            | 500      |      |      | 500      | μA   |            |    |
|                  |                                 | Stanuby                           | DB0-DB7 at 0 V 01 VDD   | 25°C  |            |          | 100  |      |          | 100  | μΑ         |    |
| kovo             | Supply voltage se               | nsitivity,                        | ΔV <sub>DD</sub> = 10%  | Full-range  |            |          | 0.16 |      |          | 0.04 | %/%        |    |
| ks∨s             | $\Delta gain/\Delta V_{DD}$     |                                   | $\Delta A D D = 10.9$   | 25°C  |            | 0.002    | 0.02 |      | 0.001    | 0.02 | pF         |    |
| Ci               | Input capacitance<br>WR, CS     | , DB0–DB7,                        | VI = 0  |   |            |          | 5    |      |          | 5    | pF         |    |
|                  | OUT1<br>Output OUT2             | OUT1                              |   | 30  | 30         |          |      | 30   |          |      |            |    |
|                  |                                 | OUT2                              | DB0–DB7 at 0, $\overline{WR}$ and $\overline{C}$                                      | Sat0V   |            |          | 120  |      |          | 120  | ~ <b>F</b> |    |
| Co               | capacitance                     | OUT1                              | DB0–DB7 at V <sub>DD</sub> , $\overline{\text{WR}}$ and $\overline{\text{CS}}$ at 0 V |   |            |          | 120  |      |          | 120  | pF         |    |
|                  |                                 | OUT2                              |   |   |            |          | 30   |      |          | 30   |            |    |
|                  | Reference input in (REF to GND) | npedance                          |   |   | 5          |          | 20   | 5    |          | 20   | kΩ         |    |

# operating characteristics over recommended operating free-air temperature range, $V_{ref}$ = 10 V, OUT1 and OUT2 at GND (unless otherwise noted)

| PARAMETER  | TEST CONDITIONS                               | V <sub>CC</sub> = 5 V | V <sub>DD</sub> = 15 V | UNIT        |      |  |
|--|---|-----------------------|------------------------|-------------|------|--|
| FARAMETER  | TEST CONDITIONS                               | MIN MA                |                        | MIN MAX     |      |  |
| Linearity error  |   |                       | ±0.2                   | ±0.2        | %FSR |  |
| Gain error   | See Note 1                                    | Full range            | ±1.4                   | ±0.6        | %FSR |  |
| Gain error   | See Note 1                                    | 25°C                  | ±1                     | ±0.5        | %F3K |  |
| Settling time (to 1/2 LSB)   | See Note 2                                    | 100                   | 100                    | ns          |      |  |
| Propagation delay from digital input to 90% of final analog output current | See Note 2                                    | 80                    | 80                     | ns          |      |  |
| Feedthrough at OUT1 or OUT2  | $V_{ref} = \pm 10 V$ (100 kHz sinewave),      | Full range            | 0.5                    | 0.5         | %FSR |  |
| Feedinfough at 0011 of 0012  | WR and CS at 0, DB0–DB7 at 0                  | 25°C                  | 0.25                   | 0.25        | %F3K |  |
| Temperature coefficient of gain  | $T_A = 25^{\circ}C$ to $t_{min}$ or $t_{max}$ | ±0.004                | ±0.001                 | %FSR/<br>°C |      |  |

NOTES: 1. Gain error is measured using the internal feedback resistor. Nominal Full Scale Range (FSR) = V<sub>ref</sub> - 1 LSB.
2. OUT1 load = 100 Ω, C<sub>ext</sub> = 13 pF, WR at 0 V, CS at 0 V, DB0–DB7 at 0 V to V<sub>DD</sub> or V<sub>DD</sub> to 0 V.



## PRINCIPLES OF OPERATION

The AD7524M is an 8-bit multiplying D/A converter consisting of an inverted R-2R ladder, analog switches, and data input latches. Binary weighted currents are switched between the OUT1 and OUT2 bus lines, thus maintaining a constant current in each ladder leg independent of the switch state. The high-order bits are decoded and these decoded bits, through a modification in the R-2R ladder, control three equally weighted current sources. Most applications only require the addition of an external operational amplifier and a voltage reference.

The equivalent circuit for all digital inputs low is seen in Figure 1. With all digital inputs low, the entire reference current,  $I_{ref}$ , is switched to OUT2. The current source 1/256 represents the constant current flowing through the termination resistor of the R-2R ladder, while the current source  $I_{lkg}$  represents leakage currents to the substrate. The capacitances appearing at OUT1 and OUT2 are dependent upon the digital input code. With all digital inputs high, the off-state switch capacitance (30 pF maximum) appears at OUT2 and the on-state switch capacitance (120 pF maximum) appears at OUT1. With all digital inputs low, the situation is reversed as shown in Figure 1. Analysis of the circuit for all digital inputs high is similar to Figure 1; however, in this case,  $I_{ref}$  would be switched to OUT1.

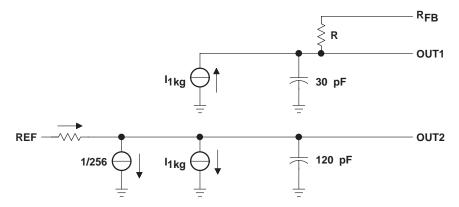
Interfacing the AD7524M D/A converter to a microprocessor is accomplished via the data bus and the  $\overline{CS}$  and  $\overline{WR}$  control signals. When  $\overline{CS}$  and  $\overline{WR}$  are both low, the AD7524M analog output responds to the data activity on the DB0–DB7 data bus inputs. In this mode, the input latches are transparent and input data directly affects the analog output. When either the CS signal or WR signal goes high, the data on the DB0–DB7 inputs are latched until the  $\overline{CS}$  and  $\overline{WR}$  signals go low again. When  $\overline{CS}$  is high, the data inputs are disabled regardless of the state of the  $\overline{WR}$  signal.

The AD7524M is capable of performing 2-quadrant or full 4-quadrant multiplication. Circuit configurations for 2-quadrant or 4-quadrant multiplication are shown in Figures 2 and 3. Input coding for unipolar and bipolar operation are summarized in Tables 1 and 2, respectively.



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#### PRINCIPLES OF OPERATION





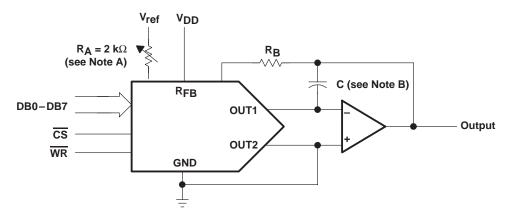
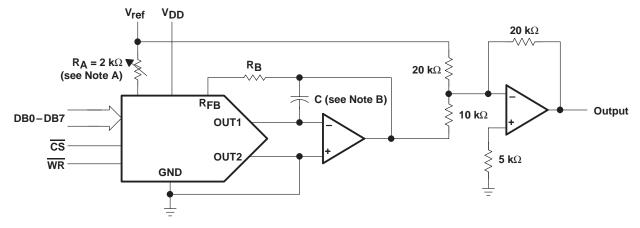


Figure 2. Unipolar Operation (2-Quadrant Multiplication)





- NOTES: A.  $\mathsf{R}_{\mathsf{A}}$  and  $\mathsf{R}_{\mathsf{B}}$  used only if gain adjustment is required.
  - B. C phase compensation (10 15 pF) is required when using high-speed amplifiers to prevent ringing or oscillation.



# PRINCIPLES OF OPERATION

| DIGITAL<br>(see N                            | - INPUT<br>IOTE 3)           | ANALOG OUTPUT  |
|--|------------------------------|--|
| MSB  | LSB                          |  |
| 1111<br>1000<br>1000<br>0111<br>0000<br>0000 | 0001<br>0000<br>1111<br>0001 | $\begin{array}{l} -V_{ref} (255/256) \\ -V_{ref} (129/256) \\ -V_{ref} (128/256) = -V_{ref} /2 \\ -V_{ref} (127/256) \\ -V_{ref} (1/256) \\ 0 \end{array}$ |

#### Table 1. Unipolar Binary Code

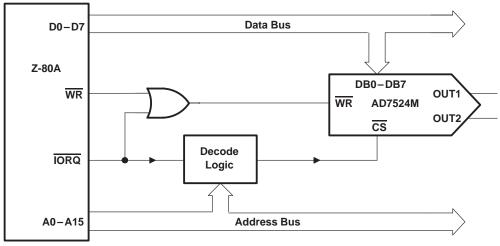
NOTES: 3. LSB = 1/256 (V<sub>ref</sub>).

#### Table 2. Bipolar (Offset Binary) Code

| DIGITAL<br>(see N                            | - INPUT<br>IOTE 4)           | ANALOG OUTPUT  |
|--|------------------------------|--|
| MSB  | LSB                          |  |
| 1111<br>1000<br>1000<br>0111<br>0000<br>0000 | 0001<br>0000<br>1111<br>0001 | V <sub>ref</sub> (127/128)<br>V <sub>ref</sub> (128)<br>0<br>-V <sub>ref</sub> (128)<br>-V <sub>ref</sub> (127/128)<br>-V <sub>ref</sub> |

NOTES: 4. LSB = 1/128 (V<sub>ref</sub>).

# microprocessor interfaces



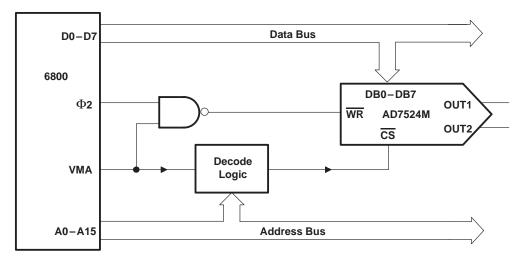




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### **PRINCIPLES OF OPERATION**





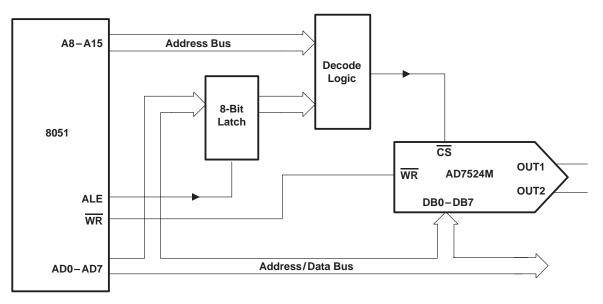


Figure 6. AD7524M-8051 Interface



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